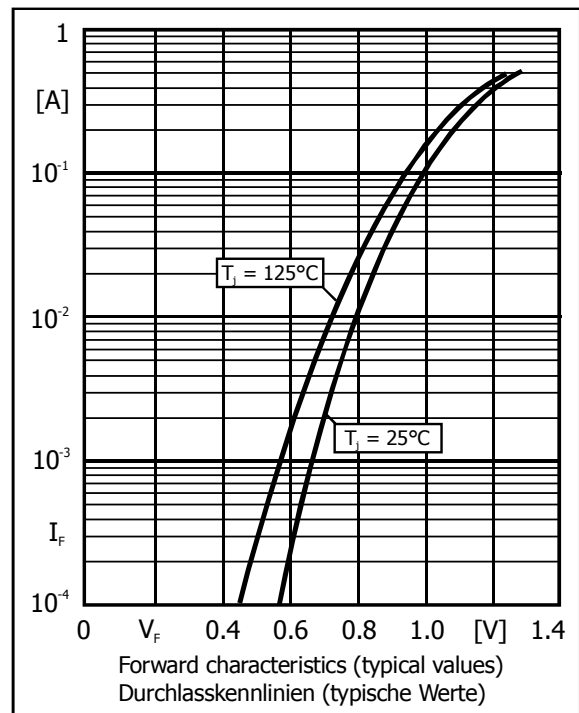
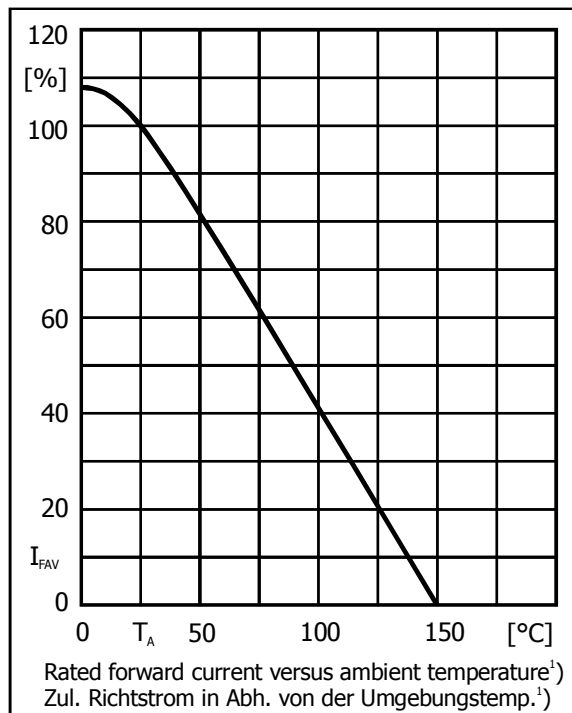


Characteristics

Kennwerte

Forward voltage Durchlass-Spannung	$T_j = 25^{\circ}\text{C}$ $I_F = 10\text{ mA}$	V_F	$< 1.0\text{ V}^1)$
Leakage current Sperrstrom	$T_j = 25^{\circ}\text{C}$ $V_R = 20\text{ V}$	I_R	$< 25\text{ nA}$
Reverse recovery time Sperrverzug	$I_F = 10\text{ mA}$ through/über $I_R = 10\text{ mA}$ to $I_R = 1\text{ mA}$	t_{rr}	$< 4\text{ ns}$
Thermal resistance junction to case Wärmewiderstand Sperrschicht – Gehäuse		R_{thC}	$< 85\text{ K/W}^2)$



1 Per diode – Pro Diode

2 Valid, if leads are kept at ambient temperature at a distance of 3 mm from case
Gültig, wenn die Anschlussdrähte in 3 mm Abstand vom Gehäuse auf Umgebungstemperatur gehalten werden